

International
IR Rectifier

SD600N/R SERIES

STANDARD RECOVERY DIODES

Stud Version

Features

- Wide current range
- High voltage ratings up to 3200V
- High surge current capabilities
- Stud cathode and stud anode version
- Standard JEDEC types

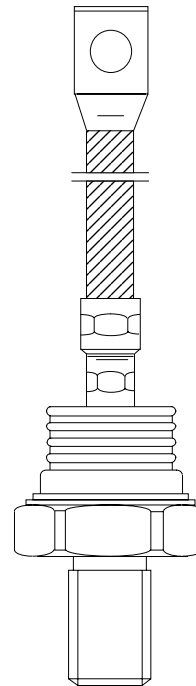
600A

Typical Applications

- Converters
- Power supplies
- Machine tool controls
- High power drives
- Medium traction applications

Major Ratings and Characteristics

Parameters	SD600N/R		Units
	04 to 20	22 to 32	
$I_{F(AV)}$	600	600	A
@ T_C	92	54	°C
$I_{F(RMS)}$	940	940	A
I_{FSM} @ 50Hz	13000	10500	A
@ 60Hz	13600	11000	A
I^2t @ 50Hz	845	551	KA ² s
@ 60Hz	772	503	KA ² s
V_{RRM} range	400 to 2000	2200 to 3200	V
T_J	- 40 to 180	- 40 to 150	°C



case style
B-8

SD600N/R Series

Bulletin I2070 rev. C 03/03

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ELECTRICAL SPECIFICATIONS

Voltage Ratings

Type number	Voltage Code	V_{RRM} , maximum repetitive peak reverse voltage V	V_{RSM} , maximum non-repetitive peak rev. voltage V	I_{RRM} max. @ $T_J = T_J$ max. mA
SD600N/R	04	400	500	35
	08	800	900	
	12	1200	1300	
	16	1600	1700	
	20	2000	2100	
	22	2200	2300	
	28	2800	2900	
	32	3200	3300	

Forward Conduction

Parameter		SD600N/R		Units	Conditions
		04 to 20	22 to 32		
$I_{F(AV)}$ Max. average forward current @ Case temperature		600	600	A	180° conduction, half sine wave
		92	54	°C	
$I_{F(AV)}$ Max. average forward current @ Case temperature		570	375	A	180° conduction, half sine wave
		100	100	°C	
$I_{F(RMS)}$ Max. RMS forward current		940	940	A	DC @ $T_C = 75^\circ\text{C}$ (04 to 20), $T_C = 36^\circ\text{C}$ (25 to 32)
I_{FSM} Max. peak, one-cycle forward, non-repetitive surge current		13000	10500	A	t = 10ms No voltage
		13600	11000		t = 8.3ms reapplied
		10900	8830		t = 10ms 100% V_{RRM}
		11450	9250		t = 8.3ms reapplied
I^2t Maximum I^2t for fusing		845	551	KA ² s	t = 10ms No voltage
		772	503		t = 8.3ms reapplied
		598	390		t = 10ms 100% V_{RRM}
		546	356		t = 8.3ms reapplied
$I^2\sqrt{t}$ Maximum $I^2\sqrt{t}$ for fusing		8450	5510	KA ² √s	t = 0.1 to 10ms, no voltage reapplied
$V_{F(TO)1}$ Low level value of threshold voltage		0.78	0.84	V	(16.7% $\times \pi \times I_{F(AV)} < I < \pi \times I_{F(AV)}$), $T_J = T_J$ max.
$V_{F(TO)2}$ High level value of threshold voltage		0.87	0.88		($I > \pi \times I_{F(AV)}$), $T_J = T_J$ max.
r_{f1} Low level value of forward slope resistance		0.35	0.40	mΩ	(16.7% $\times \pi \times I_{F(AV)} < I < \pi \times I_{F(AV)}$), $T_J = T_J$ max.
r_{f2} High level value of forward slope resistance		0.31	0.38		($I > \pi \times I_{F(AV)}$), $T_J = T_J$ max.
V_{FM} Max. forward voltage drop		1.31	1.44	V	$I_{pk} = 1500\text{A}$, $T_J = T_J$ max, $t_p = 10\text{ms}$ sinusoidal wave

Thermal and Mechanical Specifications

Parameter		SD600N/R		Units	Conditions
		04 to 20	22 to 32		
T _J	Max. junction operating temperature range	-40 to 180	-40 to 150	°C	
T _{stg}	Max. storage temperature range	-55 to 200	-55 to 200		
R _{thJC}	Max. thermal resistance, junction to case	0.1		K/W	DC operation
R _{thCS}	Max. thermal resistance, case to heatsink	0.04			Mounting surface, smooth, flat and greased
T	Max. allowed mounting torque ±10%	50		Nm	Not lubricated threads
wt	Approximate weight	454		g	
Case style		B - 8			See Outline Table

ΔR_{thJC} Conduction

(The following table shows the increment of thermal resistance R_{thJC} when devices operate at different conduction angles than DC)

Conduction angle	Sinusoidal conduction	Rectangular conduction	Units	Conditions
180°	0.012	0.008	K/W	$T_J = T_J \text{ max.}$
120°	0.014	0.014		
90°	0.017	0.019		
60°	0.025	0.026		
30°	0.042	0.042		

Ordering Information Table

Device Code

SD	60	0	N	32	P	C
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①

②

③

④

⑤

⑥

⑦

1

- Diode

2

- Essential part number

3

- 0 = Standard recovery

4

- N = Stud Normal Polarity (Cathode to Stud)
R = Stud Reverse Polarity (Anode to Stud)

5

- Voltage code: Code x 100 = V_{RRM} (See Voltage Ratings table)

6

- P = Stud base B-8 3/4" 16UNF-2A

7

- C = ceramic cap

NOTE: For Metric Device M24 x 1.5 Contact Factory

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Outlines Table

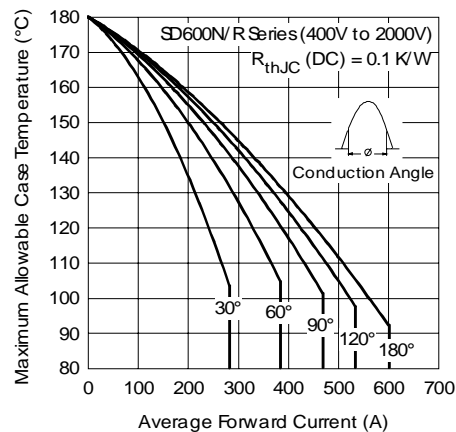
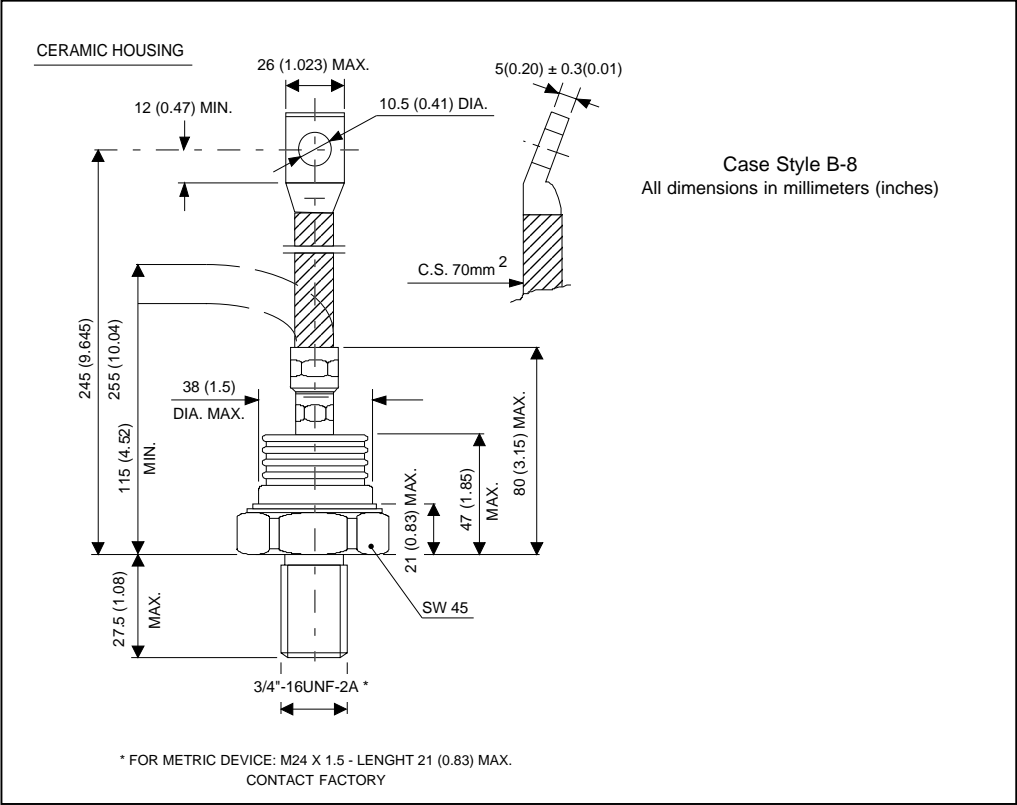


Fig. 1 - Current Ratings Characteristics

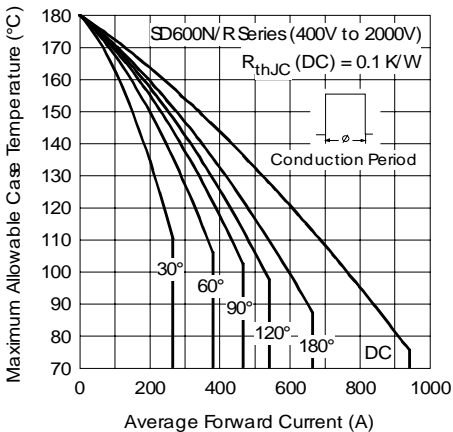


Fig. 2 - Current Ratings Characteristics

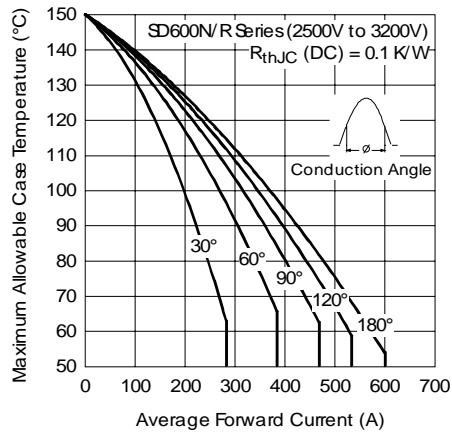


Fig. 3 - Current Ratings Characteristics

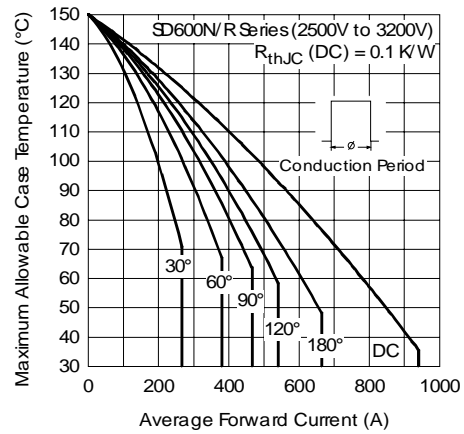


Fig. 4 - Current Ratings Characteristics

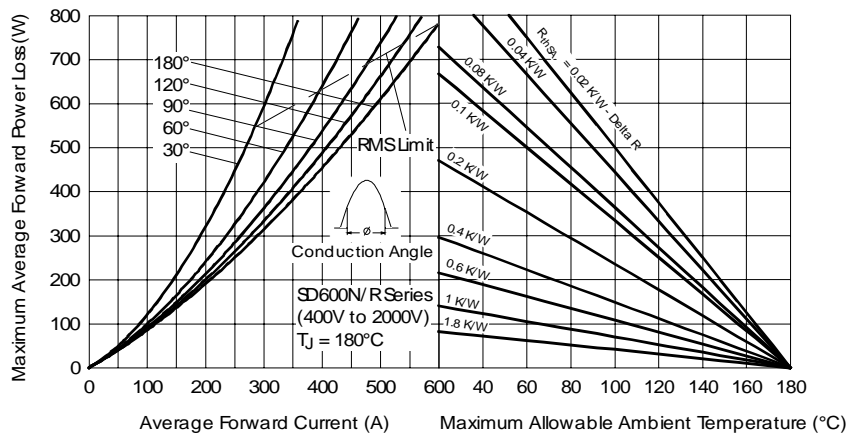


Fig. 5 - Forward Power Loss Characteristics

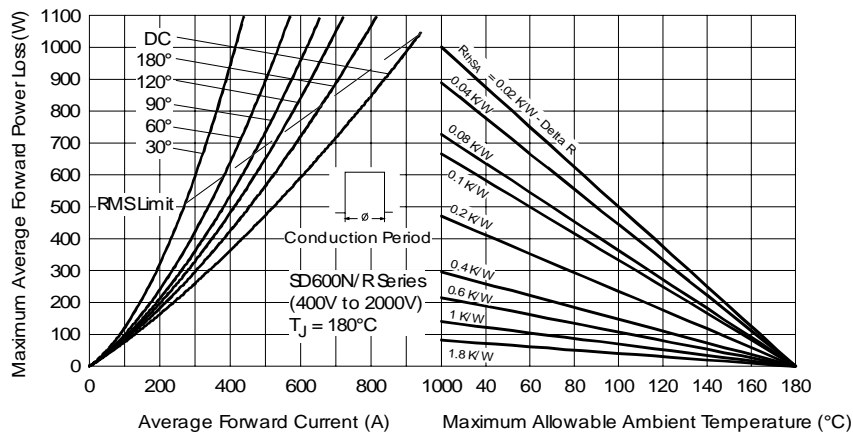


Fig. 6 - Forward Power Loss Characteristics

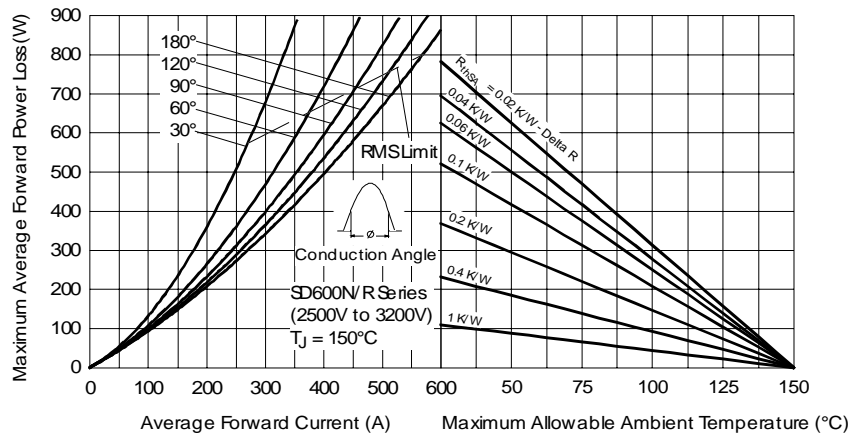


Fig. 7 - Forward Power Loss Characteristics

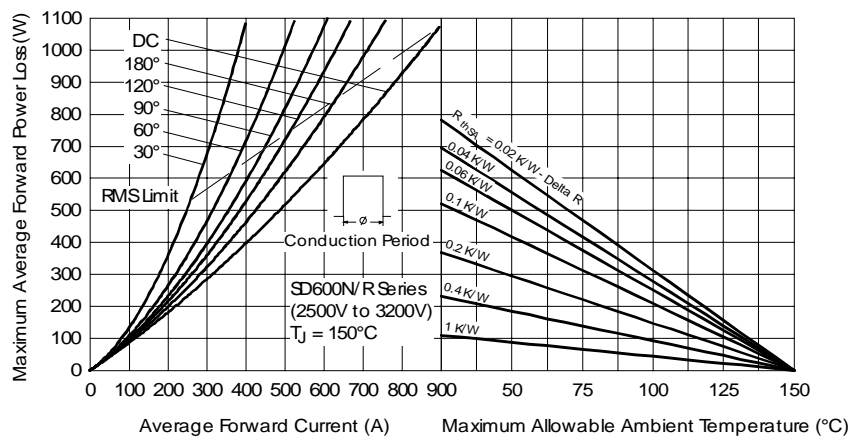


Fig. 8 - Forward Power Loss Characteristics

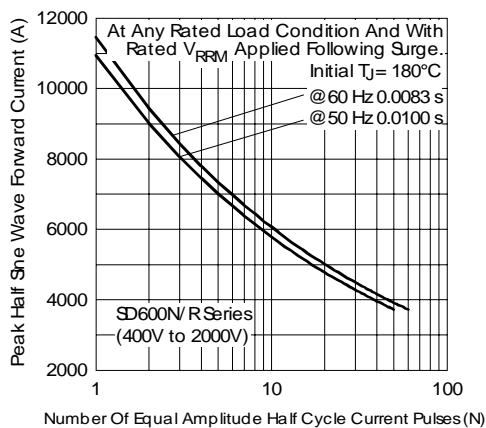


Fig. 9 - Maximum Non-Repetitive Surge Current

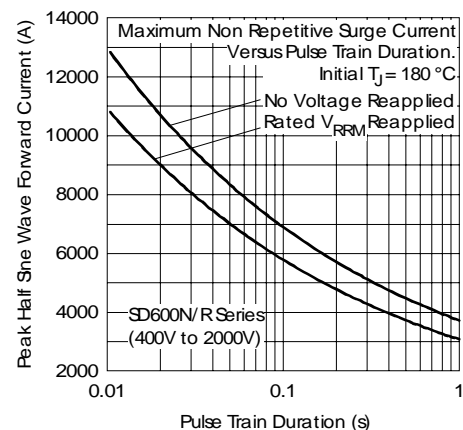


Fig. 10 - Maximum Non-Repetitive Surge Current

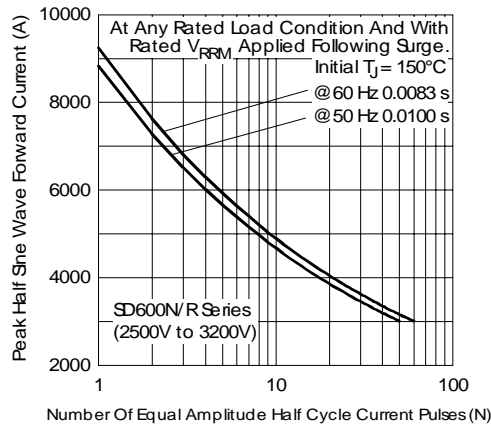


Fig. 11 - Maximum Non-Repetitive Surge Current

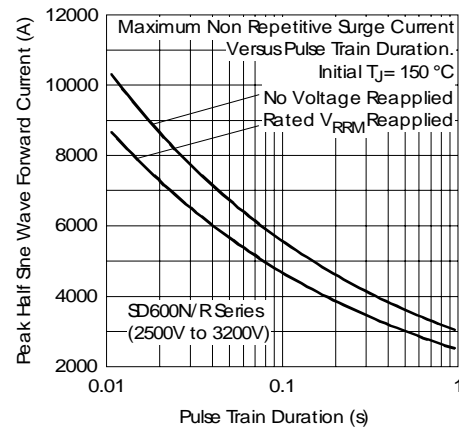


Fig. 12 - Maximum Non-Repetitive Surge Current

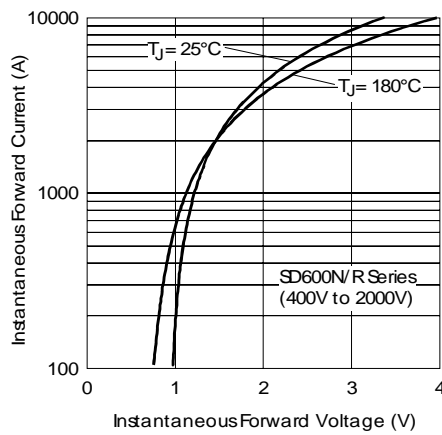


Fig. 13 - Forward Voltage Drop Characteristics

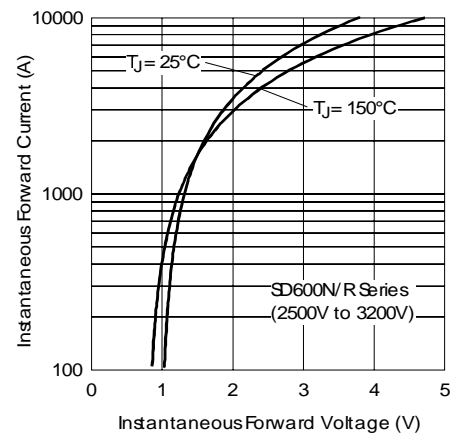


Fig. 14 - Forward Voltage Drop Characteristics

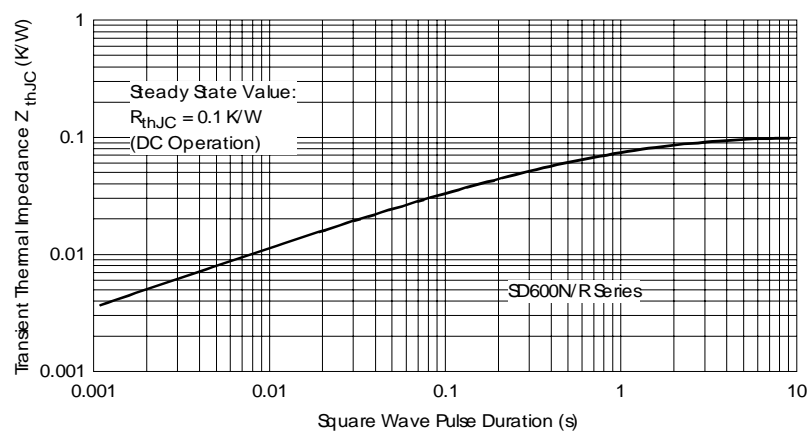


Fig. 15 - Thermal Impedance Z_{thJC} Characteristics

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Data and specifications subject to change without notice.
This product has been designed and qualified for Industrial Level.
Qualification Standards can be found on IR's Web site.

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